

QUICKSWITCH[®] PRODUCTS HIGH-SPEED CMOS 10-BIT QUICKSWITCH WITH PRECHARGED OUTPUTS

FEATURES:

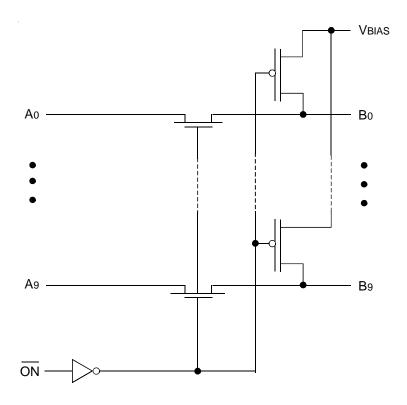
- 5 Ω bidirectional switches connect inputs to outputs
- Zero propagation delay, zero ground bounce
- Undershoot clamp diodes on all switch and control inputs
- Outputs precharge voltage to minimize signal distortion during live insertion
- TTL-compatible input and output levels
- Available in SOIC, QSOP, and TSSOP packages

DESCRIPTION:

The QS3800 is a 10-bit high-speed CMOS bus switch controlled by a single enable (\overline{ON}) input. When \overline{ON} is low, the switch is on and port A is connected to port B. When \overline{ON} is high, the switch between port A and port B is open and port B is precharged to the bias voltage. The low ON resistance (5Ω) of the QS3800 allows inputs to be connected to outputs without adding propagation delay and without generating additional noise. The QS3800 also precharges the B port to a user-selectable bias voltage to minimize live insertion noise, which is useful in VME bus applications.

The QS3800 is characterized for operation at -40°C to +85°C.

FUNCTIONAL BLOCK DIAGRAM



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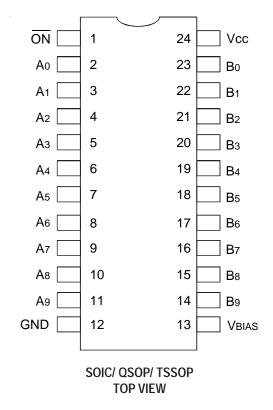
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INDUSTRIAL TEMPERATURE RANGE

HIGH-SPEED CMOS 10-BIT QUICKSWITCH WITH PRECHARGED OUTPUTS

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PINCONFIGURATION



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Supply Voltage to Ground	–0.5 to +7	V
Vbias	Bias Voltage Range	–0.5 to Vcc	V
VTERM ⁽³⁾	DC Input Voltage VIN	-0.5 to Vcc+0.5	V
VAC	AC Input Voltage (pulse width ≤20ns)	-3	V
Ιουτ	DC Output Current	120	mA
	Input Clamp Current	-50	mA
Рмах	Maximum Power Dissipation	0.5	W
Tstg	Storage Temperature	-65 to +150	°C

NOTES:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc .

CAPACITANCE (TA = +25°C, f = 1MHz, VIN = 0V, VOUT = 0V)

Pins	Тур.	Max. ⁽¹⁾	Unit
Control Inputs	3	5	рF
Quickswitch Channels (Switch OFF)	5	7	pF

NOTE:

1. This parameter is guaranteed but not production tested.

PINDESCRIPTION

Pin Names	I/O	Description
A0 - A9	I/O	Bus A
B0 - B9	I/O	Bus B
ŌN	I	Bus Switch Enable
VBIAS	I	Bias Voltage

FUNCTION TABLE⁽¹⁾

ŌN	B0 - B9	Function
L	A0 - A9	Connect
Н	VBIAS	Disconnect

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

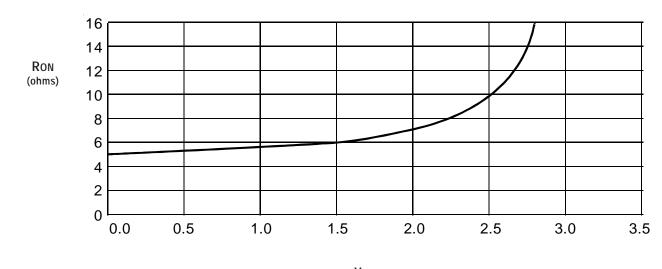
Following Conditions Apply Unless Otherwise Specified: Industrial: TA = -40° C to $+85^{\circ}$ C, Vcc = 5V ± 10%

Symbol	Parameter	Test Conditions	Min.	Тур. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2	_	_	V
VIL	Input LOW Voltage	Guaranteed Logic LOW for Control Pins	—	_	0.8	V
VBIAS	BiasVoltage	Vcc = 5V	1.3	—	Vcc	V
lo	Bias Current	VCC = $4.5V$, VBIAS = $2.4V$, VO = 0 , \overline{ON} = HIGH	0.25	_	_	mA
lin	Input Leakage Current (Control Inputs)	$0V \le VIN \le VCC$	_	—	±1	μA
loz	Off-State Current (Hi-Z)	$0V \le VOUT \le VCC$	_	_	±1	μA
Ron	Switch ON Resistance	VCC = Min., VIN = 0V, ION = 30mA	—	5	7	Ω
		Vcc = Min., Vin = 2.4V, Ion = 15mA	_	10	15	

NOTE:

1. Typical values are at Vcc = 5V and TA = 25° C.

TYPICAL ON RESISTANCE vs VIN AT Vcc = 5V



VIN (Volts)

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Max.	Unit
lcco	Quiescent Power Supply Current	Vcc = Max., VIN = GND or Vcc, f = 0	0.2	3	μΑ
ΔICC	Power Supply Current per Input HIGH ⁽³⁾	VCC = Max., VIN = 3.4V, f = 0	—	2.5	mA
ICCD	Dynamic Power Supply Current per MHz ⁽⁴⁾	Vcc = Max., A and B Pins Open, Data Inputs = GND,	—	0.25	mA/MHz
		Control Input Toggling @ 50% Duty Cycle			

NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.

2. Typical values are at Vcc = 5V and TA = 25° C.

3. Per TTL-driven input (VIN = 3.4V, control inputs only). A and B pins do not contribute to ∆Icc.

3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

$T_A = -40^{\circ}C \text{ to } +85^{\circ}C, V_{CC} = 5V \pm 10\%$

CLOAD = 50pF, RLOAD = 500Ω unless otherwise noted.

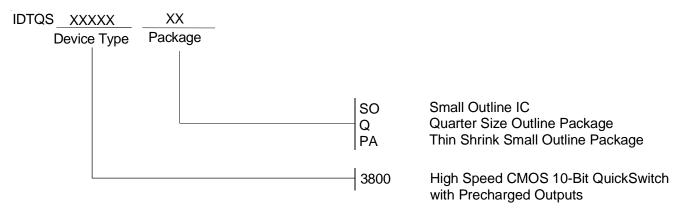
Symbol	Parameter	Test Conditions	Min. ⁽¹⁾	Тур.	Max.	Unit
tplh tphl	Data Propagation Delay ^(1,2) A to B, B to A		_	0.25	—	ns
tpzl tpzh	Switch Turn-On Delay ON to A or B	Vbias = 3V Vbias = GND	1.5	_	7.5	ns
tplz tphz	Switch Turn-Off Delay ⁽¹⁾ ON to A or B	Vbias = 3V Vbias = GND	1.5		6.5	ns

NOTES:

1. This parameter is guaranteed but not production tested.

The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns at CL = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION





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